



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Sang-jin PARK, et al.

Art Unit: 2818

Serial No. 10/830,119

Examiner: Mai Huong C. TRAN

Filed: April 23, 2004

Confirmation No. 9008

For: MAGNETIC RANDOM ACCESS MEMORY
INCLUDING MIDDLE OXIDE LAYER AND
METHOD OF MANUFACTURING THE SAME

RESPONSE TO REQUIREMENT FOR RESTRICTION

Commissioner for Patents
Alexandria, VA 22313-1450

Sir:

Responsive to the requirement set forth in the Action dated July 6, 2005, applicants hereby provisionally elect the subject matter of Group I, Claims 1-7, drawn to a semiconductor device, classified in class 257, subclass 294.

Applicants reserve the right to file divisional application(s) directed to the non-elected subject matter.

Action on the merits is solicited.

Respectfully submitted,

Date: August 8, 2005


Eugene M. Lee, Reg. No. 32,039

LEE & MORSE, P.C.
1101 WILSON BOULEVARD, SUITE 2000
ARLINGTON, VA 22209
703.525.0978 TEL
703.525.4265 FAX